

64 Mbit Mobile FCRAM™

3 V, Page Mode

MB82DP04184E-65L

■ FEATURES

- Asynchronous SRAM Interface
- Complies with Common Specifications for Mobile RAM (COSMORAM) Revision 1
- 8 Words Page Address Access Capability
- Byte Control with \overline{LB} , \overline{UB} pin
- Various Power Down Mode
 - Sleep
 - 8 Mbit Partial
 - 16 Mbit Partial
- Chip/Wafer Business

■ PRODUCT OPTIONS

| | | |
|---------------------------------|-------------------|--------|
| Part Number | MB82DP04184E | |
| Speed Version | 65L | |
| Organization | 4 M WORD × 16 BIT | |
| Supply Voltage | 2.6 V to 3.1 V | |
| Read/Write Cycle Time (Min.) | 65 ns | |
| Address Access Time (Max.) | 65 ns | |
| Page Address Access Time (Max.) | 20 ns | |
| Active Current (Max.) | T.B.D. | |
| Standby Current (Max.) | T.B.D. | |
| Power Down Current (Max.) | Sleep | T.B.D. |

Note: FCRAM is a trademark of Fujitsu Limited, Japan.